

Features :

- Isolated mounting base 3000V~
- Solder joint technology with increased power cycling capability
- Space and weight saving

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

V_{DSM}, V_{RSM}	V_{DRM}, V_{RRM}	品名
900V	800V	MD55T80S
1100V	1000V	MD55T100S
1300V	1200V	MD55T120S
1500V	1400V	MD55T140S
1700V	1600V	MD55T160S
1900V	1800V	MD55T180S

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}\text{C})$	VALUE			UNIT
				Min.	Typ.	Max.	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Single side cooled, $T_c=85^{\circ}\text{C}$	125			55	A
$I_{T(RMS)}$	RMS on-state current					86	A
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			15	mA
I_{TSM}	Surge on-state current	$V_R=60\%V_{RRM}, t=10\text{ms}$ half sine,	125			1.7	kA
I^{2t}	I^{2t} for fusing coordination		125			14.5	$10^3\text{A}^2\text{s}$
V_{TO}	Threshold voltage		125			0.75	V
r_T	On-state slope resistance					4.05	$\text{m}\Omega$
V_{TM}	Peak on-state voltage	$I_{TM}=170\text{A}$	25			1.60	V
dV/dt	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM}$	125			1000	$\text{V}/\mu\text{s}$
di/dt	Critical rate of rise of on-state current	Gate source 1.5A $t_r \leq 0.5\mu\text{s}$ Repetitive	125			200	$\text{A}/\mu\text{s}$
I_{GT}	Gate trigger current	$V_A=12\text{V}, I_A=1\text{A}$	25	30		200	mA
V_{GT}	Gate trigger voltage			0.6		2.5	V
I_H	Holding current			10		250	mA
I_L	Latching current					1000	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125			0.20	V
$R_{th(j-c)}$	Thermal resistance Junction to case	D.C. Single side cooled per chip				0.470	$^{\circ}\text{C}/\text{W}$
$R_{th(c-h)}$	Thermal resistance case to heatsink	D.C. Single side cooled per chip				0.160	$^{\circ}\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz,R.M.S., $t=1\text{min}, I_{iso}:1\text{mA(MAX)}$		3000			V
F_m	Terminal connection torque(M5)			2.4		3.0	$\text{N}\cdot\text{m}$
	Mounting torque(M6)			3.5		5.0	$\text{N}\cdot\text{m}$
T_{vj}	Junction temperature			-40		125	$^{\circ}\text{C}$
T_{stg}	Stored temperature			-40		125	$^{\circ}\text{C}$
W_t	Weight				100		g
Outline		M16					

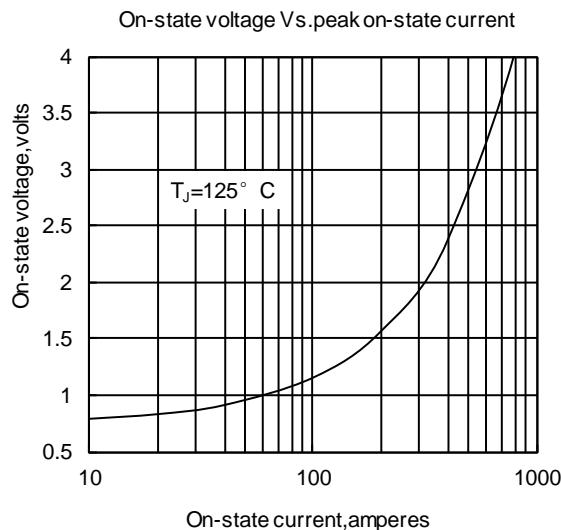


Fig1

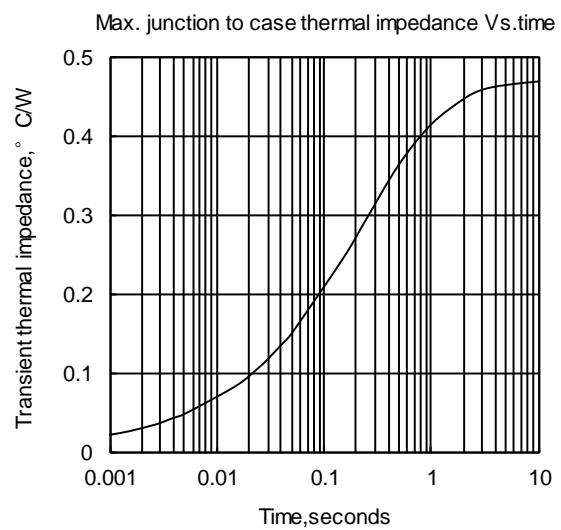


Fig2

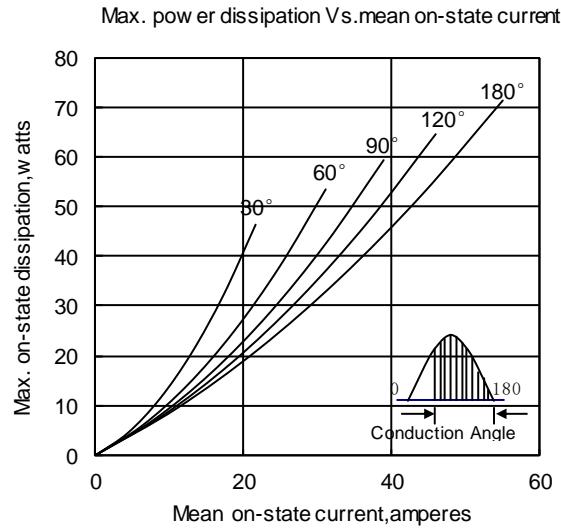


Fig3

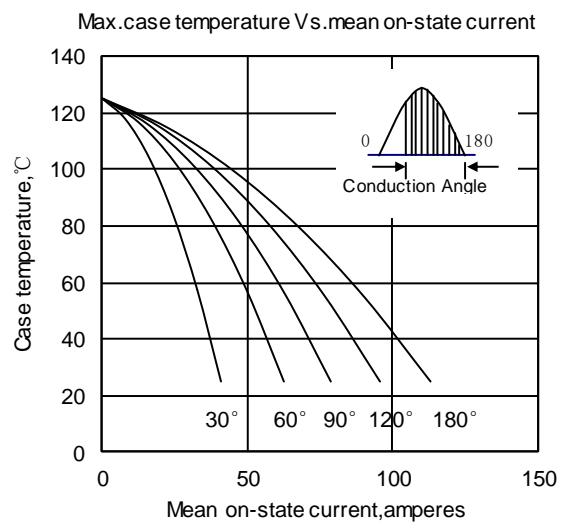


Fig4

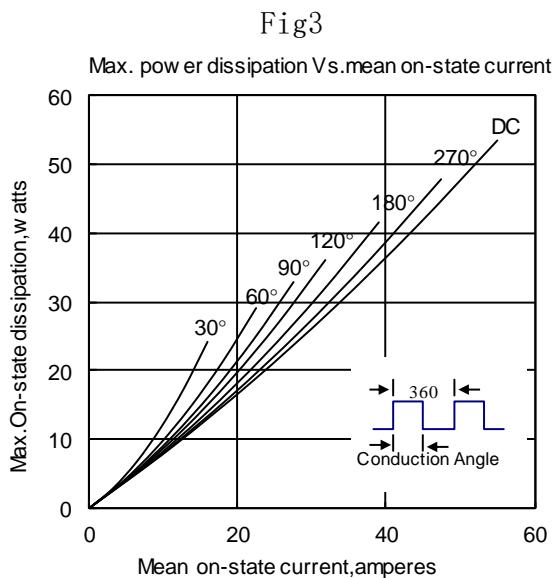


Fig5

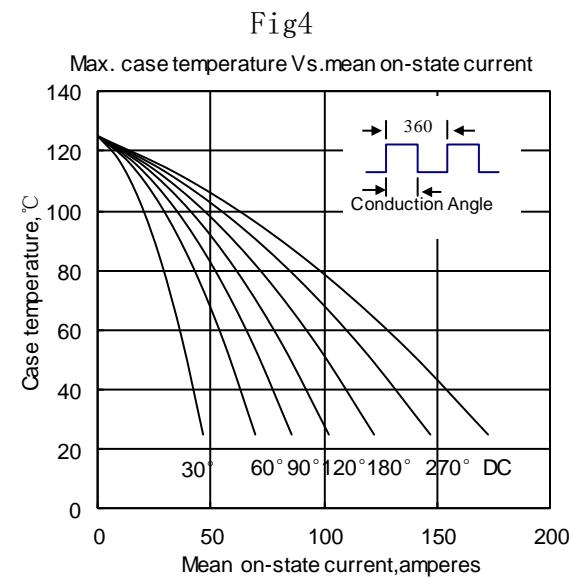


Fig6

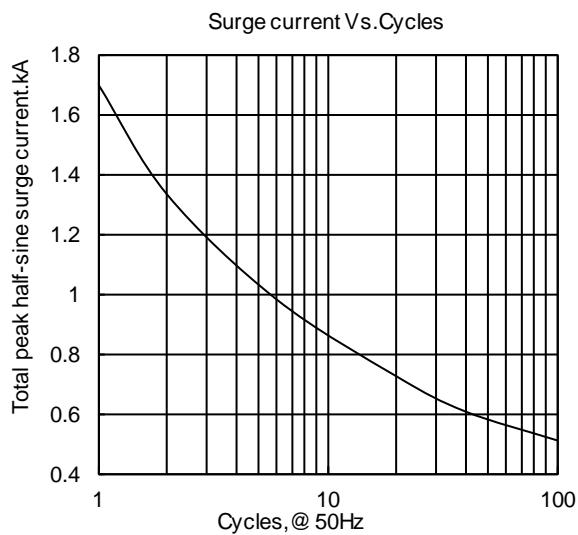


Fig7

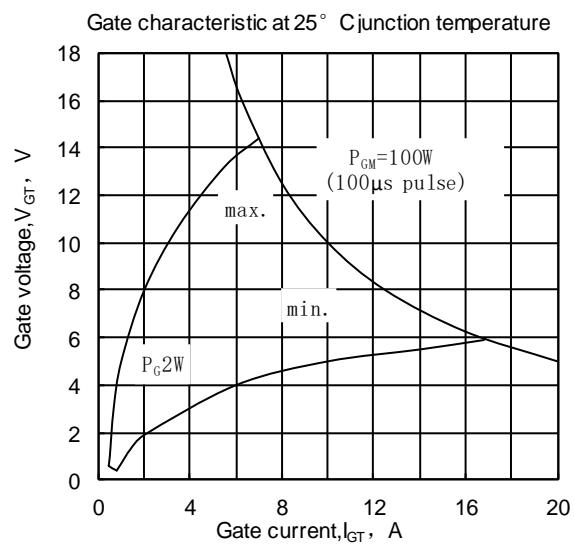


Fig8

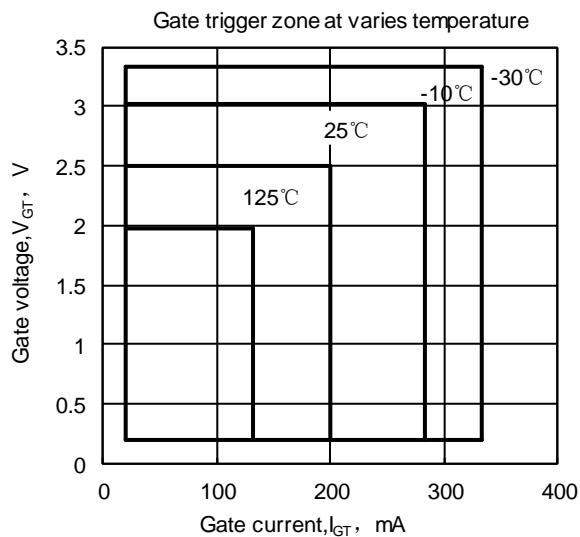
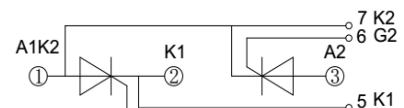
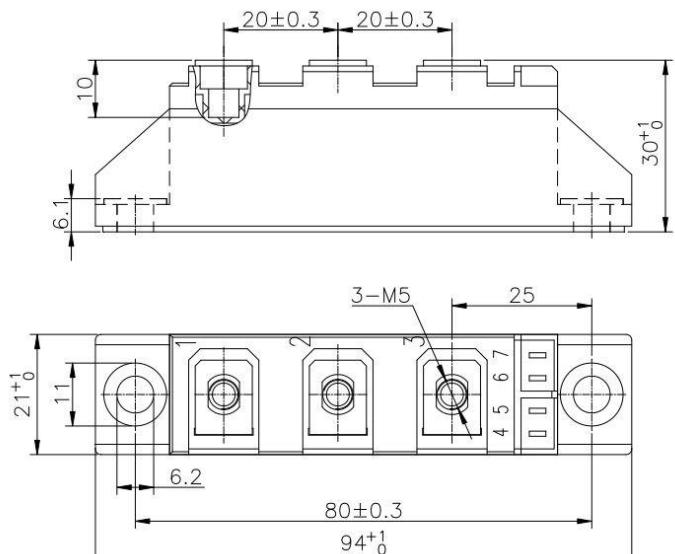


Fig9



MD55T**S

Unmarked dimensional tolerance : $\pm 0.5\text{mm}$